OT407

Four-quadrant triac, enhanced noise immunityRev. 01 — 19 May 2008P

Product data sheet

1. Product profile

1.1 General description

Passivated sensitive gate triac in a SOT54A (wide pitch) plastic package

1.2 Features

- Sensitive gate Gate triggering in four quadrants Direct interfacing to logic level ICs Direct interfacing to low power gate drive circuits High blocking voltage to 800 V Enhanced immunity to voltage transients and noise **1.3 Applications** Home appliances Low power motor control Low power loads in industrial process Low power AC fan speed controllers control 1.4 Quick reference data IGT \leq 5 mA V_{DRM} ≤ 800 V I_{TSM} \leq 12.5 A (t = 20 ms) I_{GT} \leq 7 mA (T2–G+)
- **Pinning information** 2.

I $I_{T(RMS)} \le 1 \text{ A}$

Pin	Description	Simplified outline	Graphic symbol
1	main terminal 2 (T2)		N 1
2	gate (G)		T2-T1
3	main terminal 1 (T1)		G sym051

SOT54A



3. Ordering information

Table 2. Ordering information						
Type number	Package					
	Name	Description	Version			
OT407	-	plastic single-ended leaded (through hole) package; 3 leads (wide pitch)	SOT54A			

4. Limiting values

Table 3. Limiting values

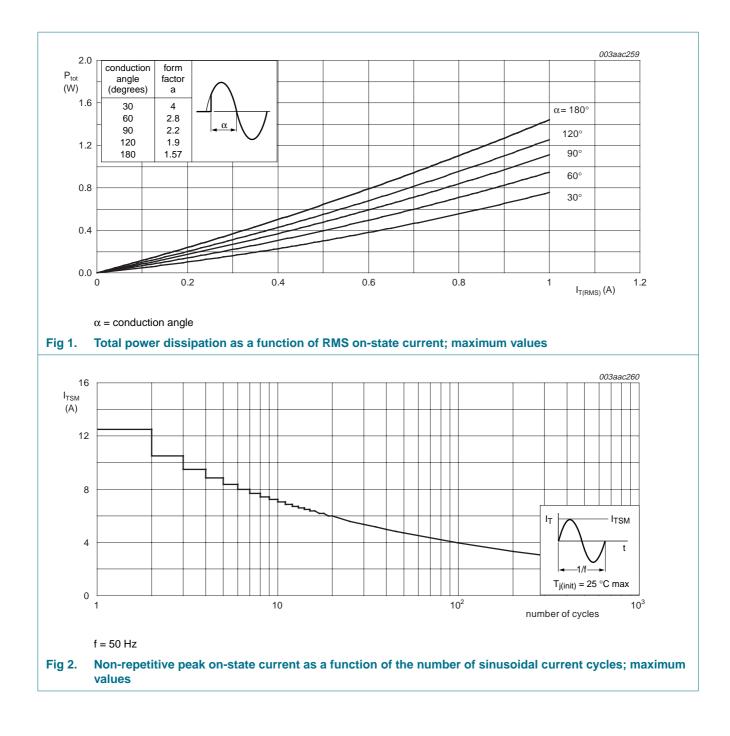
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
V _{RRM}	repetitive peak reverse voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; $T_{lead} \le 38 \text{ °C}$; see Figure 4 and 5	-	1	А
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_j = 25 \text{ °C}$ prior to surge; see Figure 2 and 3			
		t = 20 ms	-	12.5	А
		t = 16.7 ms	-	13.8	А
l ² t	I ² t for fusing	t _p = 10 ms	-	1.28	A ² s
dl _T /dt	rate of rise of on-state current	$I_{TM} = 1 \text{ A}; I_G = 20 \text{ mA};$ $dI_G/dt = 0.2 \text{ A}/\mu\text{s}$			
		T2+ G+	-	50	A/μs
		T2+ G–	-	50	A/μs
		T2– G–	-	50	A/μs
		T2– G+	-	10	A/μs
I _{GM}	peak gate current		-	1	А
P _{GM}	peak gate power		-	2	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	+150	°C
Tj	junction temperature		-	125	°C

NXP Semiconductors

Four-quadrant triac, enhanced noise immunity

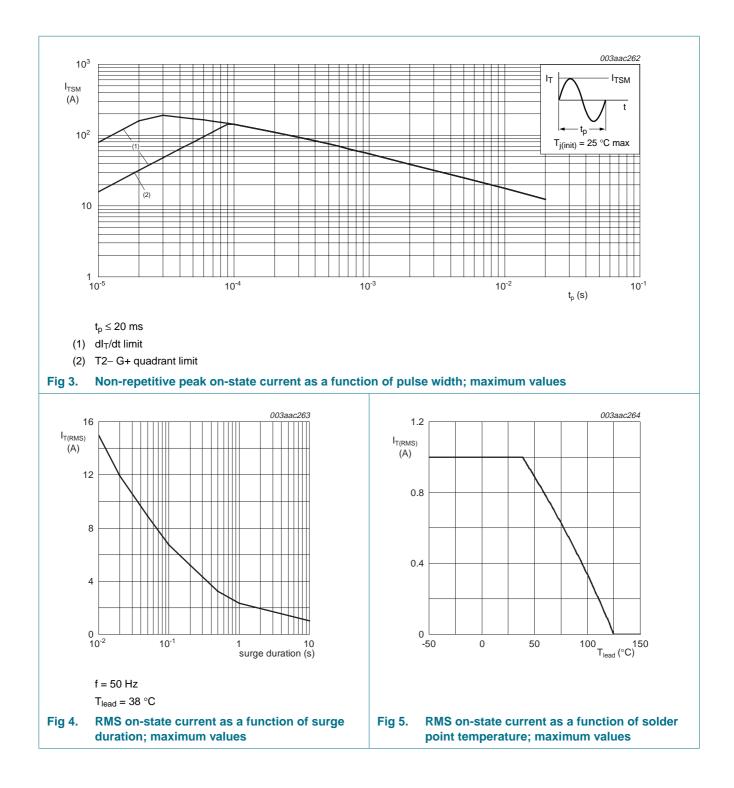
OT407



NXP Semiconductors

Four-quadrant triac, enhanced noise immunity

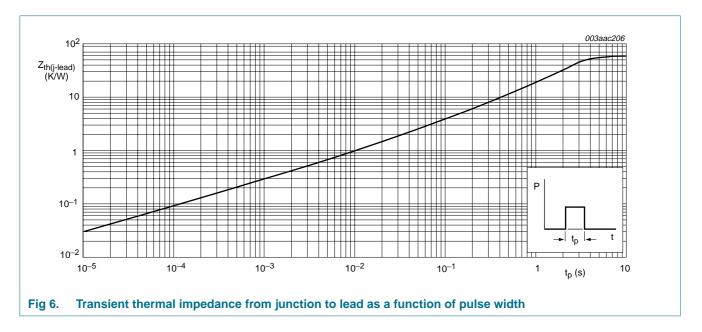
OT407



OT407

Thermal characteristics 5.

Table 4.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th}(j-\text{lead})}$	thermal resistance from junction to lead	full cycle; see <u>Figure 6</u>	-	-	60	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	full cycle; printed-circuit board mounted; lead length = 4 mm	-	150	-	K/W



OT407_1 **Product data sheet**

OT407

6. Static characteristics

Table 5. Static characteristics

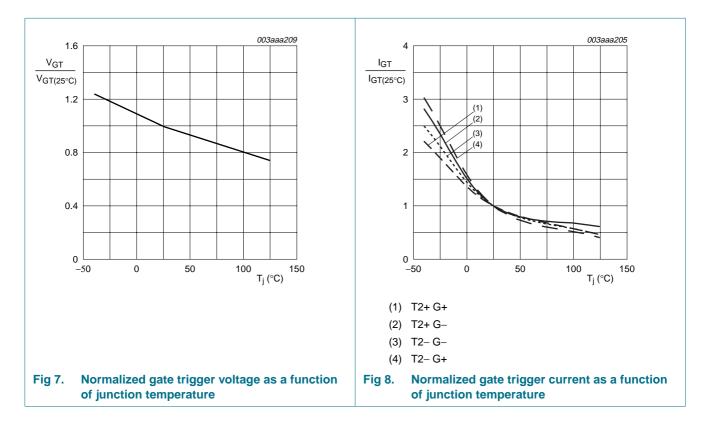
 $T_i = 25 \circ C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ see } \frac{\text{Figure 8}}{100000000000000000000000000000000000$				
		T2+ G+	0.25	-	5	mA
		T2+ G–	0.25	-	5	mA
		T2– G–	0.25	-	5	mA
		T2– G+	0.35	-	7	mA
IL latching current		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ see } \frac{\text{Figure } 10}{10}$				
		T2+ G+	-	-	10	mA
		T2+ G–	-	-	25	mA
		T2– G–	-	-	10	mA
		T2– G+	-	-	10	mA
I _H	holding current	$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ see } \frac{\text{Figure } 11}{100000000000000000000000000000000$	-	-	10	mA
VT	on-state voltage	I _T = 1 A; see <u>Figure 9</u>	-	1.3	1.6	V
V _{GT} gat	gate trigger voltage	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ see } \frac{\text{Figure 7}}{100000000000000000000000000000000000$	-	-	1.3	V
		$V_D = V_{DRM}; I_T = 0.1 \text{ A}; T_j = 125 ^{\circ}\text{C}$	0.2	-	-	V
I _D	off-state current	$V_D = V_{DRM(max)}; T_j = 125 \ ^{\circ}C$	-	-	0.5	mA

OT407

7. Dynamic characteristics

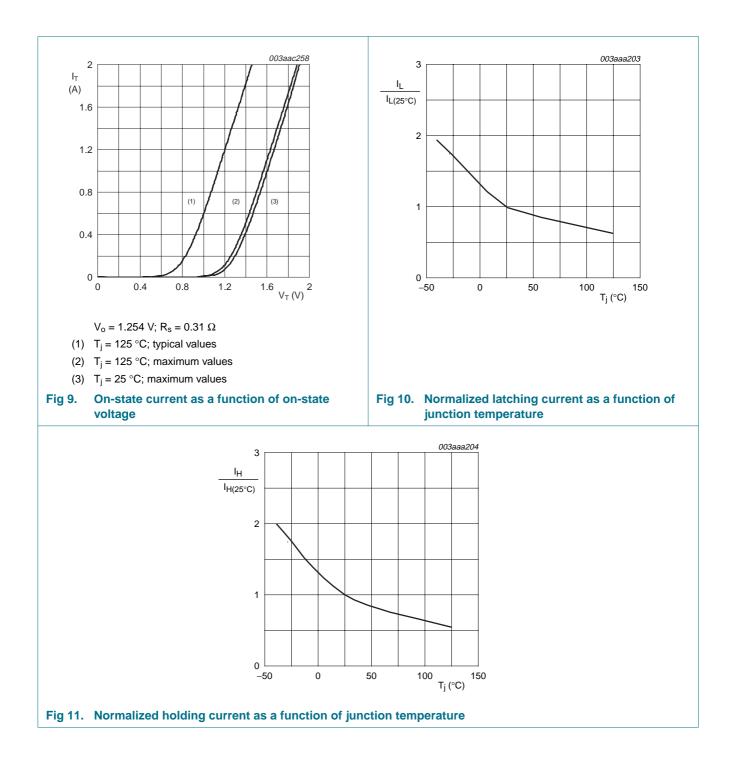
Table 6.	Dynamic characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 0.67 $V_{DRM(max)}$; T_j = 110 °C; exponential waveform; gate open circuit	20	-	-	V/µs
dV _{com} /dt	rate of change of commutating voltage	V_{DM} = 400 V; T _j = 110 °C; I _{TM} = 1 A; dI _{com} /dt = 0.44 A/ms	1	-	-	V/µs



NXP Semiconductors

Four-quadrant triac, enhanced noise immunity

OT407



OT407

8. Package outline

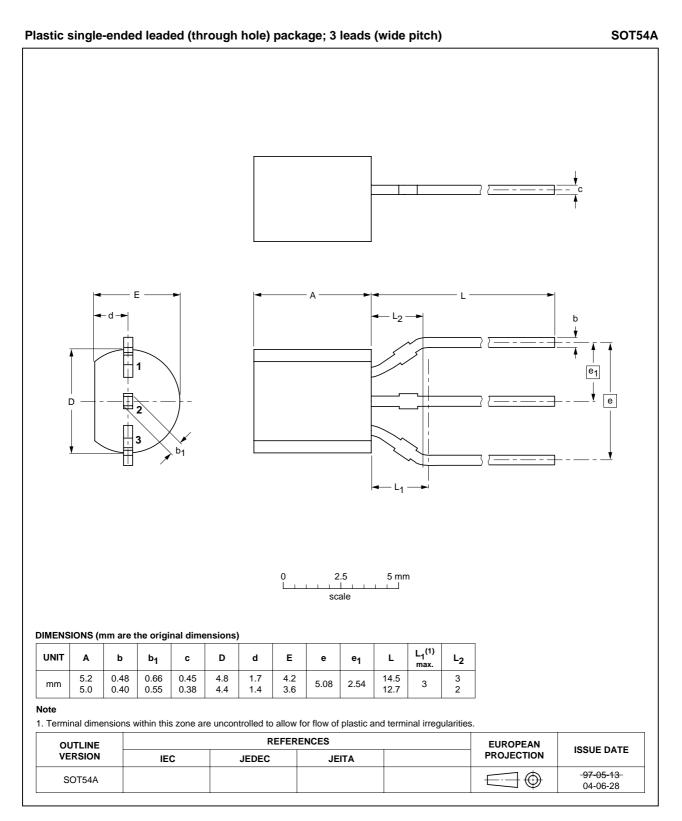


Fig 12. Package outline SOT54A

9. Revision history

Table 7. Revision hist	Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes		
OT407_1	20080519	Product data sheet	-	-		

10. Legal information

10.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

10.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

10.3 Disclaimers

General — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental

damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

10.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

11. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

OT407

12. Contents

1	Product profile 1
1.1	General description
1.2	Features
1.3	Applications 1
1.4	Quick reference data 1
2	Pinning information 1
3	Ordering information 2
4	Limiting values 2
5	Thermal characteristics 5
6	Static characteristics 6
7	Dynamic characteristics 7
8	Package outline 9
9	Revision history 10
10	Legal information 11
10.1	Data sheet status 11
10.2	Definitions 11
10.3	Disclaimers
10.4	Trademarks 11
11	Contact information 11
12	Contents 12

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2008.

All rights reserved.

For more information, please visit: http://www.nxp.com For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 19 May 2008 Document identifier: 0T407_1



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Triacs category:

Click to view products by WeEn Semiconductor manufacturer:

Other Similar products are found below :

BT137-600-0Q OT415Q 2N6075A NTE5688 BTA2008W-800D,135 D31410 BT136-600,127 BT137B-800,118 BTA140-600,127 BTA208-800B,127 MAC97A6,116 BTA420-800BT,127 BTA201W-800E,115 BTA26-800CWRG BTA41-800BRG TMA164P-L TMA166P-L TMA54S-L BT137-600E,127 BTA140-800,127 BTB16-600CW3G TMA84S-L Z0109MN,135 T825T-6I T1635T-6I T1220T-6I NTE5638 ACST1235-8FP BT134-600D,127 BT134-600G,127 BT136X-600E,127 BT139X-800,127 BTA204X-800C,127 BTA216-600E,127 BTA316X-600E/DG,12 BTA316X-800C,127 BT134-600D,127 BT134-600E,127 BT137X-600D,127 BT139X-600E,127 BTA08-600BW3G BTA201-800ER,126 BTA208X-1000B,127 BTA316X-800E,127 NTE56008 NTE56017 NTE56018 NTE56059 NTE5608 NTE5609